

INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Not for submission under 37 CFR 1.99)	Application Number		10557820
	Filing Date		2005-11-23
	First Named Inventor	Kwan Young HAN	
	Art Unit	2894	
	Examiner Name	TRAN, TONY	
	Attorney Docket Number	P2614US00	

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	2	2004-521506	JP		2004-07-15	OSRAM OPTO SEMICONDUCTORS GMBH & CO. OHG	Corresponds to International Patent Application Publication No. 02/084749	<input type="checkbox"/>
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	4	02/084749	WO		2002-10-24	OSRAM OPTO SEMICONDUCTORS GMBH & CO. OHG	Corresponds to Japanese Patent Application Publication No. 2004-521506	<input type="checkbox"/>
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